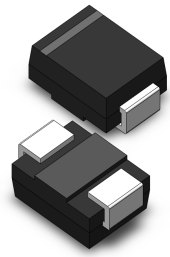
US1AB - US1MB

SURFACE MOUNT ULTAFAST RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V
CURRENT: 1.0 A



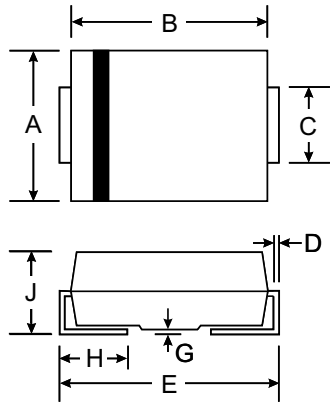
Features

- Glass Passivated Die Construction
- Diffused Junction
- Ultra-Fast Recovery Time for High Efficiency
- Low Forward Voltage Drop, High Current Capability, and Low Power Loss
- Ideally Suited for Automated Assembly
- Plastic Material: UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: SMB/DO-214AA, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)

RoHS COMPLIANT



SMB(DO-214AA)		
Dim	**Min**	**Max**
A	3.30	3.94
B	4.06	4.70
C	1.91	2.21
D	0.15	0.31
E	5.00	5.59
G	0.10	0.20
H	0.76	1.52
J	2.00	2.62
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	US1AB	US1BB	US1DB	US1GB	US1JB	US1KB	US1MB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T_T = 75°C	I_O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	30							A
Forward Voltage Drop @ I_F = 1.0A	V_{FM}	1.0			1.3	1.7			V
Peak Reverse Current @ T_A = 25°C at Rated DC Blocking Voltage @ T_A = 100°C	I_{RM}	5.0 100							μA
Reverse Recovery Time (Note 2)	t_{rr}	50				75			ns
Typical Junction Capacitance (Note 1)	C_j	20				10			pF
Typical Thermal Resistance, Junction to Terminal	$R_{\theta JT}$	30							°C/W
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150							°C

Notes: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A.

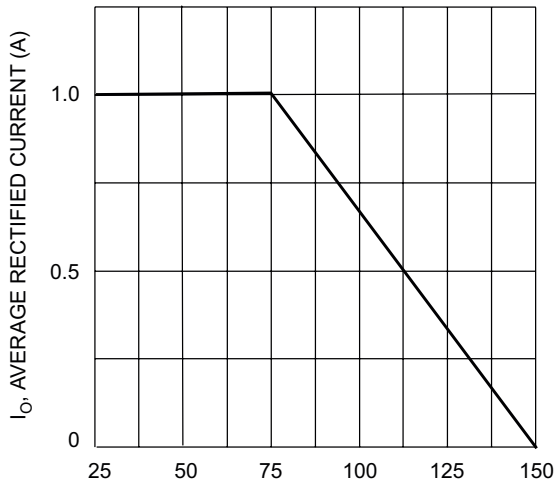


Fig. 1 Forward Current Derating Curve

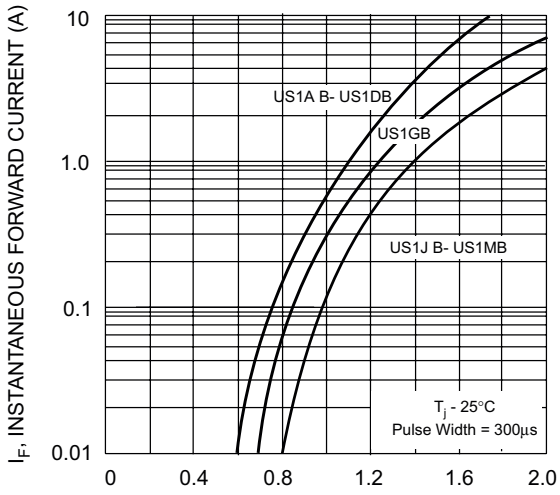


Fig. 2 Typical Forward Characteristics

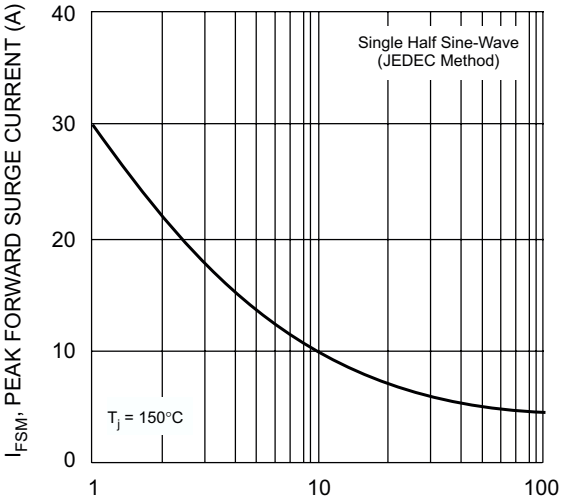


Fig. 3 Forward Surge Current Derating Curve

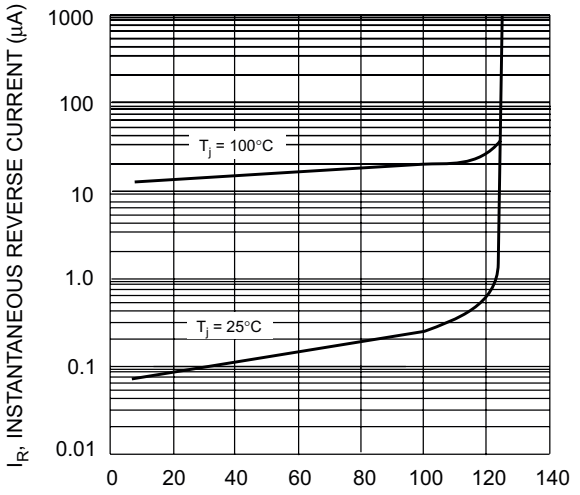
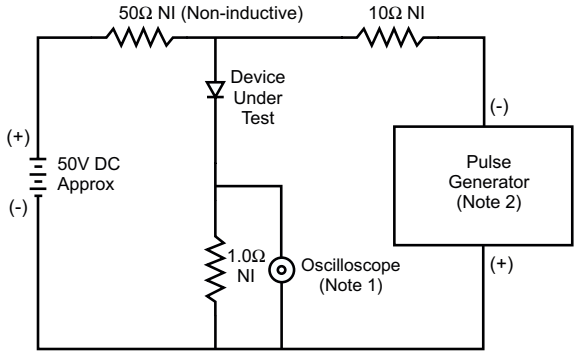


Fig. 4 Typical Reverse Characteristics



Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.

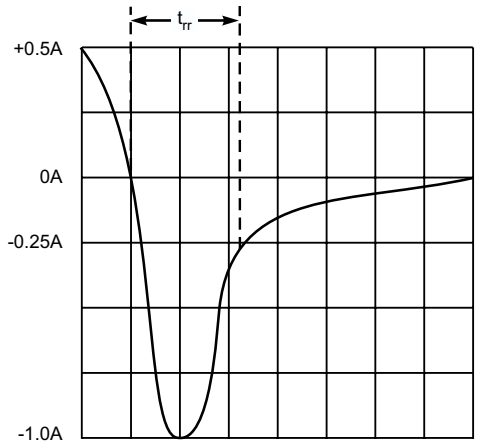


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit